NOVEL EXCITONIC STATES AND PHOTOLUM INESCENCE IN QUANTUM HALL SYSTEMS

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1. IN TRODUCTION

Photolum inescence (PL) in quantum Hallsystem shasbeen studied form ore than a decade [1{3}. The possibility of extracting from the experimental data information about correlations within the underlying two-dimensional electron gas (2DEG) in a high magnetic eld has stimulated their e ort. For the ideal theoretical model, in which electrons and holes lie on the same defect free 2D layer at extremely high magnetic eld, the PL spectrum is predicted to consist of a single line, resulting from radiative decay of a neutral exciton (X), and to give no information about electronelectron correlations [4]. This results from a \hidden symmetry associated with the equality of magnitudes of the particle-particle interactions, $V_{ee} = V_{hh} = V_{eh}$.

In realistic systems, the admixture of higher Landau levels (LL's) by the Coulomb interaction, the alteration of the interactions by form factors associated with nite quantum well width, and the nite separation of the electron and hole layers by a built-in or an applied electriceld lead to a much richer spectrum. Both neutral) excitons contribute to PL in fractional quantum Hall systems (X) and charged (X $\frac{1}{3}$ [3]. In the ideal model only the triplet X _{td} (with electronic at lling factors spin S = 1) is bound and it is non-radiative (subscript d denotes dark). In real experim ental system s, both the singlet, X $_{\rm s}$, and triplet, X $_{\rm t}$, have one orm one bound states. The PL intensity of the X td ground state is non-zero, but it is weak compared to the X s and X . In fact, it was observed only recently [3], when special care (e.g., very low tem perature) was taken to detect its weak PL signal. In order to understand the PL process in real systems, we study small systems by numerical diagonalization (in spherical geom etry). For the sim plest system s, the Hilbert space is not restricted to the lowest LL as in the ideal theoretical model, but linear combinations containing up to ve LL's are employed. The Coulomb interaction is modied so as to mim ic that of a sym m etric quantum well of width w = 11.5 nm. For systems containing m ore than three electrons and one hole, we fall back to the single LL approximation,

but we allow the electrons and holes to reside on distinct 2D layers separated by a distance d. This breaks the \hidden symmetry" in the simplest way, but it is a reasonable approximation only for the highest magnetic elds.

 $\frac{1}{3}$ were done for electron systems which are The num errical studies [5] at maximally spin polarized (except for the spin reversed electron of the X_s). It is known that for = 1 the ground state is spin polarized, and the lowest energy excitations are spin waves (SW 's). However, when is slightly smaller than unity, a \spin hole," h, in the = 1 level is present, and it can spontaneously create and bind a SW [6]. Depending on the Zeem an energy, Ez, the ground state will contain either free spin holes or \antiskyrm ions," S + (bound states of one or m ore SW 's and the h). For slightly larger than unity, the reversed spin electrons, e_R (above the = 1 led level) can form skyrm ions, S , states containing one or m ore SW 's bound to e_R . We review some results on spin excitations within the ideal model [7], with the thought of simply replacing on of the spin holes of the = 1 states by a valence band hole, v. In this ideal model the spin hole, h, and the valence band hole, v, are distinguishable (they can be distinguished by a pseudospin), but their interactions with other charged particles are equal in magnitude. This implies that an $X^{+} = (vhe_R)^{+}$ m ade up of a v bound to a SW must exist. We consider PL resulting from this antiskym ion-like excitonic complex. For slightly smaller than unity, som e antiskym ions, S^+ , are present before introduction of the v. These will avoid the X^+ due to Coulomb repulsion, so the PL at 1 1 should be due to isolated X⁺ complexes (and X's [8]). For slightly larger than unity, some S complexes will be present before introduction of the v. It is possible that the v captures eg 's from the v creates and binds a SW to form a $(vhe_R)^+ = X^+$. The X^+ has an attractive it could decay radiatively before reaching the (X; h+) state, particularly when the initial S density is very small. From analogy with the dark triplet X td at we can guess that isolated X will be \dark," and that the v-e recombination will be primarily with majority spin electrons as suggested by Cooper and Chklovskii [8]. De nitive predictions will require num erical work based on more realistic models than used in much of their work. This makes the present work qualitative and suggestive, and not intended for detailed comparison with experiment.

2. ENERGY SPECTRUM AND PL FOR

It has become rather standard to diagonalize numerically the Coulomb interaction for a nite system of N electrons conned to a spherical surface which contains at its center a magnetic monopole of strength 2Q ux quanta [9]. In the ideal theoretical model only states of the lowest LL are included. For realistic experimental systems (having a nite quantum well width w in a nite magnetic eld B) both higher LL's and the modication for the Coulomb matrix elements associated with the envelope functions of the quantum well must be included.

In Fig. 1 we present the energy spectrum for a simple 2e + v system at 2Q = 20 evaluated in the ideal theoretical model and excluding E_Z [5]. The solid dots are triplet states (S = 1), and the open circles are singlets (S = 0). The state labeled

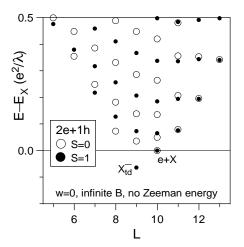


Figure 1. Energy spectrum (energy E vs.angularm om entum L) of the 2e+ v system in the lowest LL, calculated on a Haldane sphere for monopole strength 2Q=20. E_X is the exciton energy, and is the magnetic length.

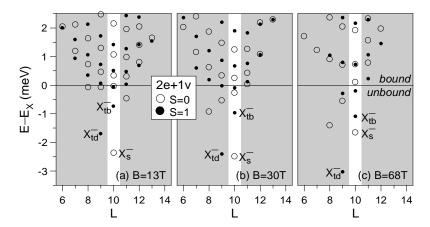


Figure 2. Same as Fig. 1, but for a realistic GaAs well of width w = 11.5 nm at the nite values of magnetic eld B as shown. The Zeem an energy has been included, and ve LL's for both electrons and hole have been used in the diagonalization.

e + X at angular momentum L=10 is a \multiplicative state" consisting of an unbound electron and an X . Notice that only one bound state (X $_{\rm td}$) occurs. It is at L=9 and is called the \dark triplet" because it is forbidden to decay radiatively.

In Fig. 2 sim ilar results are presented for a realistic system consisting of a sym metric GaAs quantum well of width w = 11:5 nm at the nite values of the magnetic eld B = 13, 30, and 68 T. The appropriate electron Zeem an splitting has been included. To achieve even qualitative agreement with experimental data, it has also been necessary to include a number of higher LL's, particularly at the lower magnetic elds. Five LL's were needed to obtain convergence in our calculations.

In Fig. 2c, at the high m agnetic eld of 68 T, the X $_{\rm td}$ at L = 9 is still the lowest energy state, but singlet and another triplet bound states occur at L = 8, 9, and 10. The singlet at L = 8 (no label) and L = 10 (X $_{\rm s}$), and the triplet at L = 10 (X $_{\rm tb}$) have roughly half the binding energy of the X $_{\rm td}$ ground state. As the m agnetic eld

is lowered, the X $_{\rm S}$ at L = 10 m oves down in energy relative to the triplet states, becoming the ground state for B smaller than 30 T (as shown in Figs. 2b and a). This is in agreement with the results obtained by W hittaker and Shields [10]. The spectra are quite sensitive to the experimental parameters. The well width wenters the Coulomb interaction [5] through V (r) = $e^2 = \frac{1}{r^2 + d^2}$, where d is proportional to w. The cyclotron frequencies ! ce (B) and ! cv (B) for the electrons and valence hole, and the Zeem an energy, E $_{\rm Z}$ (B), are taken from experiment, after Refs. [11,12].

Because exact diagonalization gives the eigenfunctions as well as the eigenvalues, it is straightforward to evaluate matrix elements of the PL operator $\hat{L}=d^2r^{\circ}_{e}(r)^{\circ}_{v}(r)$ between an initial Ne+ v state $_{i}$ and nal (N=1)e states $_{f}$. $_{e}^{\circ}$ and $_{v}^{\circ}$ are the annihilation operators for an electron and valence hole respectively. The transition oscillator strength [13] is proportional to jh $_{f}$ jL j $_{i}$ i j . For an isolated X= (where N=2), angular momentum conservation forbids the lowest triplet (X $_{td}$) from decaying radiatively. The singlet X $_{s}$ and the excited triplet X $_{tb}$ (\b" stands for \bright") both have nite (and comparable) oscillator strengths. These radiative states appear in the light color area at L=10 in Fig.2.

When additional electrons are present (N > 2) radiative decay of the X $_{\rm td}$ is not strictly forbidden, since in the recombination process an unbound electron can scatter, changing the momentum of the nal state. However, it was found that for $\frac{1}{3}$ such decays are weak because Laughlin correlations of the X with unbound electrons inhibit close collisions. The amplitude for radiative decay of the X $_{\rm td}$ is estimated [5] to be smaller by one or more orders of magnitude than those of the X $_{\rm s}$ and X $_{\rm tb}$. It was suggested in [5] that the X $_{\rm td}$ would be dicult to see in PL, and that the non-crossing peaks observed by Hayne et al. [14] were the X $_{\rm s}$ and X $_{\rm tb}$. The presence of impurities relaxes the L = 0 selection rule, and the X $_{\rm td}$ peak is clearly observed at very low temperature where the excited X $_{\rm tb}$ and X $_{\rm s}$ states are sparsely populated [3]. The agreement of experiment [3] and the numerical predictions [5] reinforce the hope of using PL to understand correlations in quantum Hall systems.

3. FRACTIONALLY CHARGED EXCITONS

For systems containing m ore than two or three electrons and a valence hole, it is discult to include the admixture of higher LL's caused by C oulom b interactions. However, the \hidden symmetry" can be broken by separating the e and v planes by a nite length d. Because only the lowest LL is included, such a simple model will be useful only at the highest magnetic elds. When d is measured in units of magnetic length = hc=eB, we can identify three regimes: strong (e(v) coupling when d 1; weak coupling when d 1.

In the strong coupling region, neutral (X) and charged triplet excitons (X) are formed due to the strong e-v interactions. Neutral excitons in their L=0 ground state are almost decoupled from the remaining N 1 electron system. At d=0, the hidden symmetry holds, and the excitons are completely decoupled, these states are called multiplicative states. The X is a charged Fermion that interacts with the remaining N 2 electrons. The generalized composite Fermion (CF) picture [15] describes the low lying excitations and the Laughlin correlations very well.

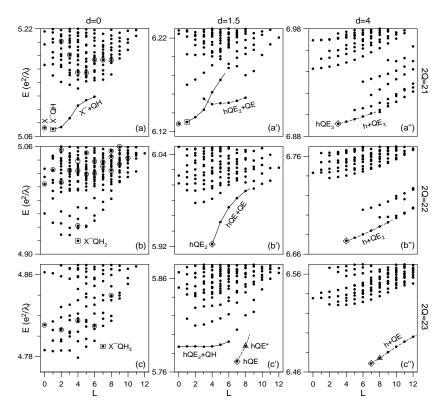


Figure 3. Energy spectra (energy E vs. angular m om entum L) of the 9e+v system in the lowest LL, calculated on a Haldane sphere for dierent monopole strengths 2Q = 21, 22, and 23, and e-v layer separations d = 0, 1.5, and 4. Lines and open symbols mark the low-energy states containing dierent bound excitonic complexes.

For d 1, the e-v interaction is a weak perturbation on the energies of the N electron system. The low energy spectrum contains bands obtained by adding the angular m om entum of the hole ($l_{\rm v}=Q$) to that of the low lying quasiparticle states of the electrons, obtained from the CF picture or from num erical diagonalization [13].

For interm ediate coupling, the e-v interaction is not strong enough to bind a full electron, but bound states of one or m ore Laughlin quasielectrons (QE) do occur. These are referred to as fractionally charged excitons (FCX) or anyon excitons.

In Fig. 3 we display the energy spectra for a 9e + v system at 2Q = 21, 22,and 23, for d = 0, 1.5, and 4. This data is taken from Ref. [16]. It is worth noting that for d = 0, the X and the X appear at each value of 2Q, while for d = 4only bound states of the valence hole and Laughlin quasielectrons (QE) occur. In fram e (a) the low lying state at L = 0 is a multiplicative state consisting of one decoupled neutral X and a Laughlin condensed state of the remaining eight electrons $=\frac{1}{3}$ state]. A band of states extending 1) = 21 for this Laughlin from L = 1 to L = 6 consists of an Xwith l_x $=\frac{5}{2}$ and a single Laughlin quasihole (QH) with $l_{QH} = \frac{7}{2}$. The solid line drawn through these states represents the pseudopotential V_{X} , $_{OH}$ (L) of the interacting X {QH pair. Initially, this band of states was incorrectly interpreted as a neutral exciton interacting with a magnetoroton [17]. The generalized CF picture [15] gives a simple and natural interpretation of all of the low lying states for all values of the param eter d. In fram e (b") the nine

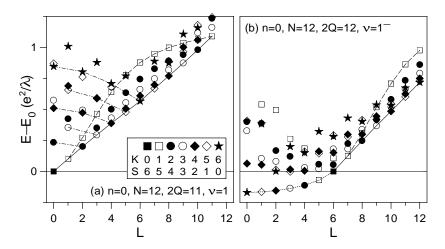


Figure 4. Energy spectra (energy E vs. angular momentum L) of the spin unpolarized 12e system in the lowest LL, calculated on a Haldane sphere for monopole strength 2Q=11 (a) and 12 (b).

electron system contains two QE's. Since $l_{QH}=Q$ (N 1) = 3 and $_{QL}=l_{QH}+1$, therefore the lowest CF shell is led by $2l_{QH}+1=7$ of the CF's leaving two as QE's in the 1st excited CF shell. The allowed values of the total angular momentum of their pair are $L_{2QE}=1$ 3 5 7. In the mean eld CF picture, these pair states would form a degenerate band. Exact diagonalization (which includes QE-QE interactions beyond mean eld) gives the ordering of the energies E (L_{2QE}) as E (7) < E (3) < E (5) < E (1). The interaction of the valence hole (with angular momentum $l_h=Q=11$) with the QE pair leads to four bands, each increasing with $L=L_{2QE}+L_h$. Detailed discussion of all these spectra is given in Ref. [16]. In this review we restrict the discussion to a few illustrative examples.

4. SP IN EXCITATIONS NEAR = 1

In order to understand the excitonic complexes that can be formed near lling factor = 1, it is rst necessary to study the elementary excitations that can occur in the absence of valence band holes. For = 1, the lowest energy excitations are spin ip excitations which create an e_R in the same n=0 LL leaving behind an h in the otherwise lled = 1 state. Even when $E_Z=0$, the Coulomb exchange energy will spontaneously break the spin (";#) symmetry giving a polarized ground state.

In Fig. 4a we show the low lying spin excitations of the = 1 state (with E $_{\rm Z}$ taken to be zero) for a system of N = 12 electrons [7]. The solid square at L = 0 is the spin polarized = 1 ground state with spin S = 6. The symbol K = $\frac{1}{2}$ N S is the number of spin ips away from the fully spin polarized state. The band of open squares connected by a dashed line gives the SW dispersion " $_{\rm SW}$ (L). The angular momentum L is related to wave number k by L = kR, where R is the radius of the sphere. con ned. The SW consists of a single $e_{\rm R}$ h pair; its dispersion can be evaluated analytically [18]. The solid circles, open circles, etc. represent states containing 2, 3, ::: spin ips (i.e., 2, 3, ::: $e_{\rm R}$ h pairs). Dot-dashed lines connect low lying states

with equal numbers of spin ips. It is interesting to note the almost straight line connecting the lowest energy states at 0 $\,$ L $\,$ 6. This can be interpreted as band of K SW 's each with $l_{\text{SW}} = 1$ with L = K . The near linearity suggests that these K SW 's are very nearly non-interacting in the state with L = K .

In Fig. 4b we present the low energy spectrum for =1 (i.e., a single spin hole in the =1 state). In both Fig. 4a and b only the lowest energy states at each L and S are shown. O fparticular interest in Fig. 4b is the band of states with L = S = Q K and negative energy. These are antiskyrm ion states, $S_K^+ = K e_R + (K + 1)h$, bound states of one h and K SW 's [6,7]. They are analogous to interband charged excitons [5], but they can be equilibrium states not subject to radiative decay at the appropriate value of E $_Z$. Skyrm ion states are $S_K^- = K h + (K + 1)e_R$. Electron-hole sym metry requires their existence for > 1.

It has been dem onstrated [7] that in the fractional quantum H all regime analogous excitations occur with QER and QH replacing e_R and h of the integral quantum H all case. SW 's, skyrm ions, and antiskyrm ions made from Laughlin quasiparticles occur for $\frac{1}{3}$. The most stable skyrm ion or antiskyrm ion size depends weakly on the quantum well width for the 1 state, but for 3, 5, ::: the well width w must be of the order of a few times the magnetic length in order to obtain stable bound states of SW 's and h's or e_R 's [7,19]. As reported in Ref. [20], the admixture of higher LL's caused by the C oulom b interaction weakly a ects the skyrm ion energy spectrum, particularly when the nite well width w is also taken into account.

The skyrm ion and antiskyrm ion states S_K are quite analogous to the excitonic X_K states of valence band holes interacting with conduction band electrons. In the ideal theoretical model, a valence hole has exactly the same interactions as a spin hole in the = 1 state of the conduction band. In fact these two types of holes can probably be distinguished by an pseudospin as is done for electrons on dierent layers of a bilayer system [21]. The spectrum and possible condensed states of a multicom ponent Ferm ion liquid containing electrons, X_1 , X_2 , etc., has been considered in Ref. [15]. Exactly the same ideas are applicable to a liquid of electrons and skyrm ions or antiskyrm ions of dierent sizes. The only dierence is that $S_1 = S_2 + S_3 = S_3 + S_3$

When there are N $_{\rm h}$ spin holes in the = 1 level (or N $_{\rm e}$ reversed spin electrons in addition to the lled = 1 level) and when N $_{\rm h}$ (or N $_{\rm e}$) is much smaller than N = 2Q+1, the degeneracy of the lled lowest LL, then the most stable conguration will consist of N $_{\rm h}$ antiskyrm ions (or N $_{\rm e}$ skyrm ions) of the most stable size. These antiskyrm ions (or skyrm ions) repelone another. They are positively (or negatively) charged Ferm ions with standard LL structure, so it is not surprising that they would form either a W igner lattice or a Laughlin condensed state with for the antiskyrm ion (or skyrm ion) equal to an odd denom inator fraction as discussed in Refs. [7,22,23].

5. PHOTOLUM INESCENCE NEAR = 1

In the ideal theoretical model, a valence hole acts exactly like a spin hole in the = 1 level of the conduction band. Therefore we would expect an excitonic complex consisting of K SW 's bound to the valence hole to be the lowest energy state, in the

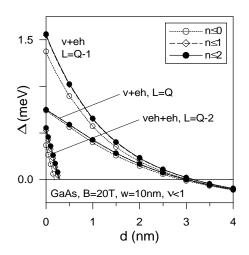


Figure 5. Binding energies of charged skyrm ion exciton $X_1^+ = v(e_R h)$ at angular momentum L = Q 1 and Q, and of charged skyrm ion biexciton $X_2^+ = v(e_R h)_2$ at L = Q 2 calculated on a sphere for monopole strength 2Q = 30 and plotted as a function of the e-v layer separation d. The parameters are for a GaAs well of width w = 10 nm at a magnetic eld B = 20 T. Dierent curves include 1{3 LL's for the v.

same way that the antiskym ion consisting of K SW 's bound to a spin hole in the = 1 level gives the lowest energy state when $E_{
m Z}$ is su ciently small. For a small num ber of valence holes, the X_K^+ = $v(e_R h)_K$ excitonic complexes formed by each valence hole will repel one another. If a small number of antiskym ions are already present (for < 1), the S+-X+ repulsion will lead to Laughlin correlations or Wigner crystallization of the multicom ponent Ferm ion liquid. Just as for the X 's in the dilute regime, the PL at low temperature will be dominated by the X_{K}^{+} ! S_{K}^{+} 0 + process, with $K^0 = K$ or K 1 depending on spin of the annihilated v (i.e., on the circular polarization of the em itted photon). This corresponds to the most stable X_{κ}^{+} undergoing radiative e-v or e_{R} -v recombination and leaving behind an antiskym ion consisting of K or K 1 SW 's bound to a spin hole of the state. Because the valence hole and the spin hole in the = 1 conduction level are distinguishable (or have di erent pseudospin) even in the ideal theoretical model this PL is not forbidden. It will be very interesting to see how realistic sample e ects (nite well width, LL admixture, nite separation between the electron and valence hole layers) alter the conclusions of the ideal theoretical model.

For 1, negatively charged skyrm ions are present before the introduction of the valence holes. The skyrm ions are attracted by the X $_{\rm K}^+$ charged exciton, but how this interaction a ects the P L can only be guessed. It is possible that the interaction of the valence hole with the skyrm ions will lead to the form ation of an X or an X $_{\rm td}$ and SW 's. The X $_{\rm td}$ will be very weakly radiative (just as in the case of $\frac{1}{3}$). However, the recombination can occur with a majority spin electron. This case was considered in Ref. [8] for the case of a single X $_{\rm td}$. The largest oscillator strength occurred for the process X $_{\rm td}$! S $_1$ + ; in other words the spin hole left in the = 1 level by the ve recombination formed a bound state with the two reversed spin electrons of the X $_{\rm td}$. Lower energy photon resulted when the two reversed spin electrons and the spin hole did not form the S $_1$ bound state.

We are currently investigating more realistic models in systems containing a small number of S 's and X 's. As a prelim inary example of our results we show in Fig. 5 the binding energy, , of the X $_1^+$ = v(e_R h) and X $_2^+$ = v(e_R h)₂ complexes for different values of the total angular momentum L as a function of the e-v layer separation d. is defined as the binding energy of the SW to a charged complex, [v(e_R h)] = E[v] + E[e_R h] E[v(e_R h)] and [v(e_R h)₂] = E[v(e_R h)] + E[e_R h] E[v(e_R h)₂]. The calculation was done for a G aA squantum well of width w = 10 nm, at a magnetic eld of 20 T, but E_Z has been om itted. The different symbols (open circles, open diamonds, and solid circles) are for calculations in which one, two, or three LL's for the valence hole have been included (inter-LL excitations of conduction electrons are less in portant due to their smaller effective mass). It is clear that the binding energies decrease with increasing e-v layer separation as expected.

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